



S1AS - S1MS

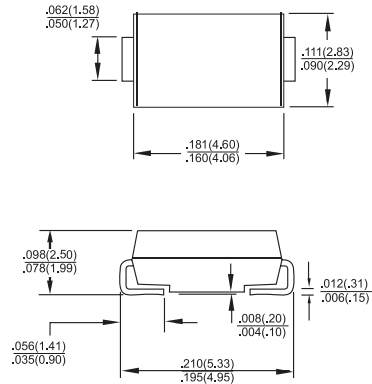
1.0 AMP. Surface Mount Rectifiers SMA/DO-214AC

Features

- ✦ For surface mounted application
- ✦ Glass passivated junction chip.
- ✦ Low forward voltage drop
- ✦ High current capability
- ✦ Easy pick and place
- ✦ High surge current capability
- ✦ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ✦ High temperature soldering: 260°C / 10 seconds at terminals
- ✦ These devices are not AEC Q101 qualified
- ✦ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ✦ Case: Molded plastic
- ✦ Terminals: Pure tin plated, lead free solderable per J-STD-002B and JESD22-B102D.
- ✦ Polarity: Indicated by cathode band
- ✦ Packaging: 12mm tape per EIA STD RS-481
- ✦ Weight: 0.064 gram



Dimensions in inches and (millimeters)

Marking Diagram



S1XS = Specific Device Code
 G = Green Compound
 Y = Year
 M = Work Month

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	S1AS	S1BS	S1DS	S1GS	S1JS	S1KS	S1MS	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ T _L = 110 °C	I(AV)	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	30							A
Maximum Instantaneous Forward Voltage @ 1.0A	V _F	1.1							V
Maximum DC Reverse Current @ T _A = 25 °C at Rated DC Blocking Voltage @ T _A = 125 °C	I _R	1.0 50							uA uA
Typical Reverse Recovery Time (Note 1)	T _{rr}	1.5							uS
Typical Junction Capacitance (Note 2)	C _j	12							pF
Typical Thermal Resistance (Note 3)	R _{θJL} R _{θJA}	30 85							°C/W
Operating Temperature Range	T _J	-55 to +150							°C
Storage Temperature Range	T _{STG}	-55 to +150							°C

- Notes:
1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
 2. Measured at 1 MHz and Applied V_R=4.0 Volts
 3. Measured on P.C. Board with 0.2" x 0.2" (5.0mm x 5.0mm) Copper Pad Areas.

RATINGS AND CHARACTERISTIC CURVES (S1AS THRU S1MS)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

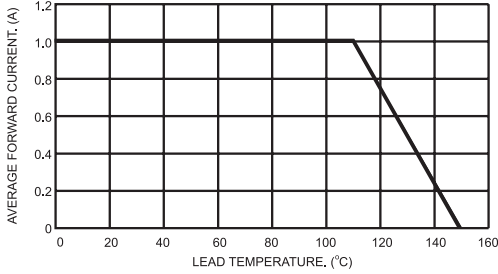


FIG.2- TYPICAL REVERSE CHARACTERISTICS

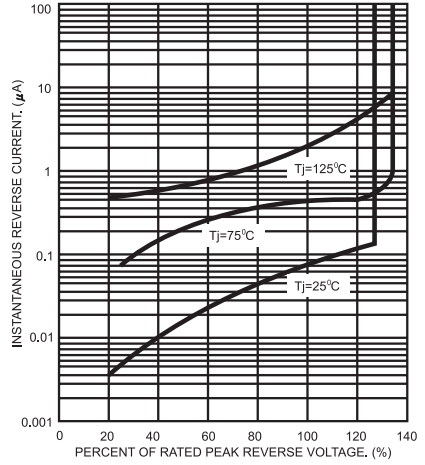


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

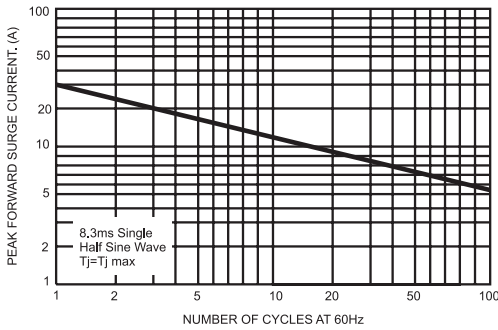


FIG.5- TYPICAL FORWARD CHARACTERISTICS

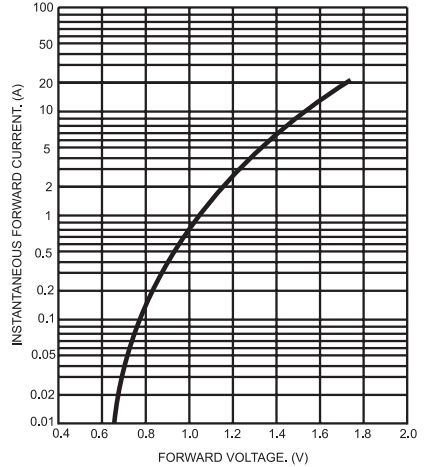


FIG.4- TYPICAL JUNCTION CAPACITANCE

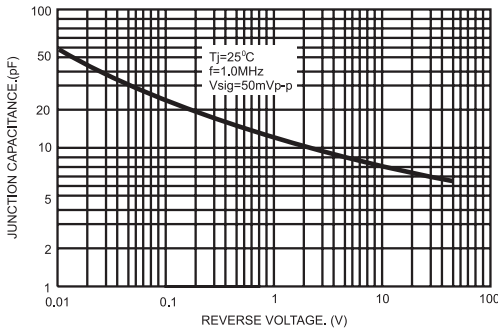


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

